SN74LVC1T45 Single-Bit Dual-Supply Bus Transceiver With Configurable Voltage Translation and 3-State Outputs

1 Features

- Available in the Texas Instruments NanoFree™ Package
- Fully Configurable Dual-Rail Design Allows Each Port to Operate Over the Full 1.65-V to 5.5-V Power-Supply Range
- V_{CC} Isolation Feature – If Either V_{CC} Input Is at GND, Both Ports Are in the High-Impedance State
- DIR Input Circuit Referenced to V_{CCA}
- Low Power Consumption, 4-µA Max I_{CC}
- ±24-mA Output Drive at 3.3 V
- I_{off} Supports Partial-Power-Down Mode Operation
- Max Data Rates
  - 420 Mbps (3.3-V to 5-V Translation)
  - 210 Mbps (Translate to 3.3 V)
  - 140 Mbps (Translate to 2.5 V)
  - 75 Mbps (Translate to 1.8 V)
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

2 Applications

- Personal Electronic
- Industrial
- Enterprise
- Telecom

3 Description

This single-bit noninverting bus transceiver uses two separate configurable power-supply rails. The A port is designed to track V_{CCA}. V_{CCA} accepts any supply voltage from 1.65 V to 5.5 V. The B port is designed to track V_{CCB}. V_{CCB} accepts any supply voltage from 1.65 V to 5.5 V. This allows for universal low-voltage bidirectional translation between any of the 1.8-V, 2.5-V, 3.3-V, and 5-V voltage nodes.

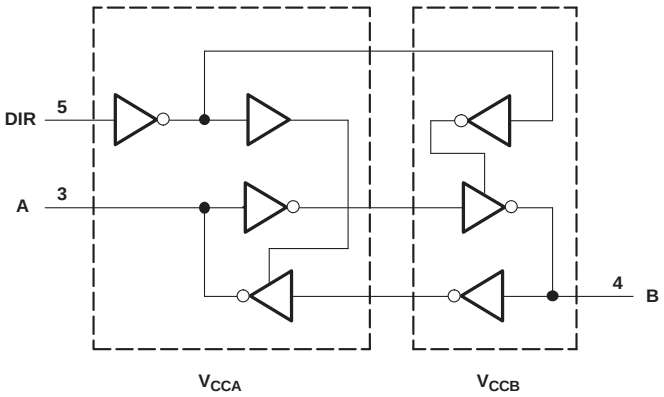
The SN74LVC1T45 is designed for asynchronous communication between two data buses. The logic levels of the direction-control (DIR) input activate either the B-port outputs or the A-port outputs. The device transmits data from the A bus to the B bus when the B-port outputs are activated and from the B bus to the A bus when the A-port outputs are activated. The input circuitry on both A and B ports always is active and must have a logic HIGH or LOW level applied to prevent excess I_{CC} and I_{CCZ}.

Device Information[1]

PART NUMBER	PACKAGE	BODY SIZE (NOM)
SN74LVC1T45	SOT (6)	2.90 mm × 1.60 mm
		2.00 mm × 1.25 mm
		1.60 mm × 1.20 mm
	DSBGA (6)	1.39 mm × 0.90 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Functional Block Diagram



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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision J (December 2013) to Revision K — **Page**

- Added *Pin Configuration and Functions* section, *ESD Ratings* table, *Feature Description* section, *Device Functional Modes*, *Application and Implementation* section, *Power Supply Recommendations* section, *Layout* section, *Device and Documentation Support* section, and *Mechanical, Packaging, and Orderable Information* section ... 1

Changes from Revision I (December 2011) to Revision J — **Page**

- Updated document to new TI data sheet format - no specification changes. ... 1
- Removed ordering information. ... 1
- Added ESD warning. ... 1

5 Description (Continued)

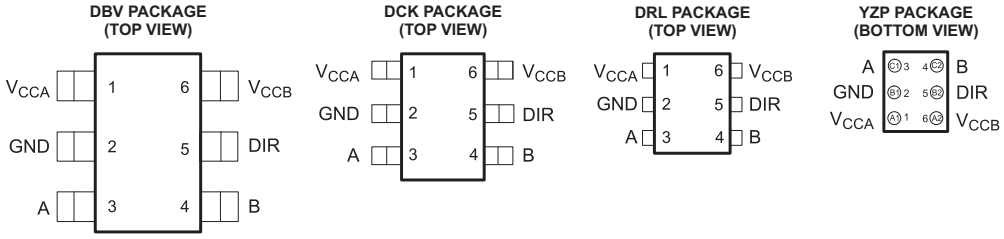
The SN74LVC1T45 is designed so that the DIR input is powered by V_{CCA}.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The V_{CC} isolation feature ensures that if either V_{CC} input is at GND, then both ports are in the high-impedance state.

NanoFree package technology is a major breakthrough in IC packaging concepts, using the die as the package.

6 Pin Configuration and Functions



See mechanical drawings for dimensions.

Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
V_{CCA}	1	p	SYSTEM-1 supply voltage (1.65 V to 5.5 V)
GND	2	G	Device GND
A	3	I/O	Output level depends on V_{CC1} voltage.
B	4	I/O	Input threshold value depends on V_{CC2} voltage.
DIR	5	I	GND (low level) determines B-port to A-port direction.
V_{CCB}	6	P	SYSTEM-2 supply voltage (1.65 V to 5.5 V)

7 Specifications

7.1 Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CCA} V_{CCB}	Supply voltage		–0.5	6.5	V
V_I	Input voltage(2)		–0.5	6.5	V
V_O	Voltage range applied to any output in the high-impedance or power-off state(2)		–0.5	6.5	V
V_O	Voltage range applied to any output in the high or low state(2)(3)	A port	–0.5	V_{CCA} + 0.5	V
		B port	–0.5	V_{CCB} + 0.5	
I_{IK}	Input clamp current	V_I < 0		–50	mA
I_{OK}	Output clamp current	V_O < 0		–50	mA
I_O	Continuous output current			±50	mA
	Continuous current through V_{CC} or GND			±100	mA
T_{stg}	Storage temperature, T_{stg}		–65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
(3) The value of V_{CC} is provided in the recommended operating conditions table.

7.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±2000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101(2)	±1000	
		Machine Model	±200	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

See (1)(2)(3)

			V_{CCI}	V_{CCO}	MIN	MAX	UNIT
V_{CCA}	Supply voltage				1.65	5.5	V
V_{CCB}					1.65	5.5	
V_{IH}	High-level input voltage	Data inputs(4)	1.65 o 1.95 V		V_{CCI} × 0.65		V
			2.3 to 2.7 V		1.7		
			3 to 3.6 V		2		
			4.5 to 5.5 V		V_{CCI} × 0.7		
V_{IL}	Low-level input voltage	Data inputs(4)	1.65 o 1.95 V			V_{CCI} × 0.35	V
			2.3 to 2.7 V			0.7	
			3 to 3.6 V			0.8	
			4.5 to 5.5 V			V_{CCI} × 0.3	

(1) V_{CCI} is the V_{CC} associated with the input port.
(2) V_{CCO} is the V_{CC} associated with the output port.
(3) All unused data inputs of the device must be held at V_{CCI} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.
(4) For V_{CCI} values not specified in the data sheet, V_{IH} min = V_{CCI} × 0.7 V, V_{IL} max = V_{CCI} × 0.3 V.

Recommended Operating Conditions (continued)

See (1)(2)(3)

			V_{CCI}	V_{CCO}	MIN	MAX	UNIT
V_{IH}	High-level input voltage	DIR (referenced to V_{CCA})(5)	1.65 to 1.95 V		V_{CCA} × 0.65		V
			2.3 to 2.7 V		1.7		
			3 to 3.6 V		2		
			4.5 to 5.5 V		V_{CCA} × 0.7		
V_{IL}	Low-level input voltage	DIR (referenced to V_{CCA})(5)	1.65 to 1.95 V			V_{CCA} × 0.35	V
			2.3 to 2.7 V			0.7	
			3 to 3.6 V			0.8	
			4.5 to 5.5 V			V_{CCA} × 0.3	
V_I	Input voltage				0	5.5	V
V_O	Output voltage				0	V_{CCO}	V
I_{OH}	High-level output current			1.65 to 1.95 V		–4	mA
				2.3 to 2.7 V		–8	
				3 to 3.6 V		–24	
				4.5 to 5.5 V		–32	
I_{OL}	Low-level output current			1.65 to 1.95 V		4	mA
				2.3 to 2.7 V		8	
				3 to 3.6 V		24	
				4.5 to 5.5 V		32	
Δt/Δv	Input transition rise or fall rate	Data inputs	1.65 to 1.95 V			20	ns/V
			2.3 to 2.7 V			20	
			3 to 3.6 V			10	
			4.5 to 5.5 V			5	
		Control inputs	1.65 to 5.5 V			5	
T_A	Operating free-air temperature				–40	85	°C

(5) For V_{CCI} values not specified in the data sheet, V_{IH} min = V_{CCA} × 0.7 V, V_{IL} max = V_{CCA} × 0.3 V.

7.4 Thermal Information

THERMAL METRIC(1)		SN74LVC1T45				UNIT
		DBV	DCK	DRL	YZP	
		6 PINS				
$R_{\theta JA}$	Junction-to-ambient thermal resistance	200.1	286.8	223.7	131.0	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	144.5	93.9	88.7	1.3	
$R_{\theta JB}$	Junction-to-board thermal resistance	45.7	95.5	58.4	22.6	
ψ_{JT}	Junction-to-top characterization parameter	36.2	1.9	5.9	5.2	
ψ_{JB}	Junction-to-board characterization parameter	25.3	94.7	58.1	22.6	
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, SPRA953.

7.5 Electrical Characteristics[1][2]

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		V_{CCA}	V_{CCB}	T_A = 25 °C			–40 to 85°C		UNIT
						MIN	TYP	MAX	MIN	MAX	
V_{OH}		I_{OH} = –100 µA	$V_I = V_{IH}$	1.65 to 4.5 V	1.65 to 4.5 V				V_{CCO} – 0.1		V
		I_{OH} = –4 mA		1.65 V	1.65 V				1.2		
		I_{OH} = –8 mA		2.3 V	2.3 V				1.9		
		I_{OH} = –24 mA		3 V	3 V				2.4		
		I_{OH} = –32 mA		4.5 V	4.5 V				3.8		
V_{OL}		I_{OL} = 100 µA	$V_I = V_{IL}$	1.65 to 4.5 V	1.65 to 4.5 V					0.1	V
		I_{OL} = 4 mA		1.65 V	1.65 V					0.45	
		I_{OL} = 8 mA		2.3 V	2.3 V					0.3	
		I_{OL} = 24 mA		3 V	3 V					0.55	
		I_{OL} = 32 mA		4.5 V	4.5 V					0.55	
I_I	DIR	$V_I = V_{CCA}$ or GND		1.65 to 5.5 V	1.65 to 5.5 V			±1		±2	µA
I_{off}	A port	V_I or V_O = 0 to 5.5 V		0 V	0 to 5.5 V			±1		±2	µA
	B port			0 to 5.5 V	0 V			±1		±2	
I_{OZ}	A or B port	$V_O = V_{CCO}$ or GND		1.65 to 5.5 V	1.65 to 5.5 V			±1		±2	µA
I_{CCA}		$V_I = V_{CCI}$ or GND, I_O = 0		1.65 to 5.5 V	1.65 to 5.5 V					3	µA
				5.5 V	0 V					2	
				0 V	5.5 V					-2	
I_{CCB}		$V_I = V_{CCI}$ or GND, I_O = 0		1.65 to 5.5 V	1.65 to 5.5 V					3	µA
				5.5 V	0 V					-2	
				0 V	5.5 V					2	
$I_{CCA} + I_{CCB}$ (see Table 1)		$V_I = V_{CCI}$ or GND, I_O = 0		1.65 to 5.5 V	1.65 to 5.5 V					4	µA
ΔI_{CCA}	A port	A port at V_{CCA} – 0.6 V, DIR at V_{CCA}, B port = open		3 to 5.5 V	3 to 5.5 V					50	µA
	DIR	DIR at V_{CCA} – 0.6 V, B port = open, A port at V_{CCA} or GND								50	
ΔI_{CCB}	B port	B port at V_{CCB} – 0.6 V, DIR at GND, A port = open		3 to 5.5 V	3 to 5.5 V					50	µA
C_i	DIR	$V_I = V_{CCA}$ or GND		3.3 V	3.3 V		2.5				pF
C_{io}	A or B port	$V_O = V_{CCA/B}$ or GND		3.3 V	3.3 V		6				pF

(1) V_{CCO} is the V_{CC} associated with the output port.
(2) V_{CCI} is the V_{CC} associated with the input port.

7.6 Switching Characteristics (V_{CCA} = 1.8 V ± 0.15 V)

over recommended operating free-air temperature range, V_{CCA} = 1.8 V ± 0.15 V (see Figure 9)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CCB} = 1.8 V ±0.15 V		V_{CCB} = 2.5 V ±0.2 V		V_{CCB} = 3.3 V ±0.3 V		V_{CCB} = 5 V ±0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	A	B	3	17.7	2.2	10.3	1.7	8.3	1.4	7.2	ns
t_{PHL}			2.8	14.3	2.2	8.5	1.8	7.1	1.7	7	
t_{PLH}	B	A	3	17.7	2.3	16	2.1	15.5	1.9	15.1	ns
t_{PHL}			2.8	14.3	2.1	12.9	2	12.6	1.8	12.2	
t_{PHZ}	DIR	A	5.2	19.4	4.8	18.5	4.7	18.4	5.1	17.1	ns
t_{PLZ}			2.3	10.5	2.1	10.5	2.4	10.7	3.1	10.9	
t_{PHZ}	DIR	B	7.4	21.9	4.9	11.5	4.6	10.3	2.8	8.2	ns
t_{PLZ}			4.2	16	3.7	9.2	3.3	8.4	2.4	6.4	
t_{PZH} (1)	DIR	A		33.7		25.2		23.9		21.5	ns
t_{PZL} (1)				36.2		24.4		22.9		20.4	
t_{PZH} (1)	DIR	B		28.2		20.8		19		18.1	ns
t_{PZL} (1)				33.7		27		25.5		24.1	

(1) The enable time is a calculated value, derived using the formula shown in the *Enable Times* section.

7.7 Switching Characteristics (V_{CCA} = 2.5 V ± 0.2 V)

over recommended operating free-air temperature range, V_{CCA} = 2.5 V ± 0.2 V (see Figure 9)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CCB} = 1.8 V ±0.15 V		V_{CCB} = 2.5 V ±0.2 V		V_{CCB} = 3.3 V ±0.3 V		V_{CCB} = 5 V ±0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	A	B	2.3	16	1.5	8.5	1.3	6.4	1.1	5.1	ns
t_{PHL}			2.1	12.9	1.4	7.5	1.3	5.4	0.9	4.6	
t_{PLH}	B	A	2.2	10.3	1.5	8.5	1.4	8	1	7.5	ns
t_{PHL}			2.2	8.5	1.4	7.5	1.3	7	0.9	6.2	
t_{PHZ}	DIR	A	3	8.1	3.1	8.1	2.8	8.1	3.2	8.1	ns
t_{PLZ}			1.3	5.9	1.3	5.9	1.3	5.9	1	5.8	
t_{PHZ}	DIR	B	6.5	23.7	4.1	11.4	3.9	10.2	2.4	7.1	ns
t_{PLZ}			3.9	18.9	3.2	9.6	2.8	8.4	1.8	5.3	
t_{PZH} (1)	DIR	A		29.2		18.1		16.4		12.8	ns
t_{PZL} (1)				32.2		18.9		17.2		13.3	
t_{PZH} (1)	DIR	B		21.9		14.4		12.3		10.9	ns
t_{PZL} (1)				21		15.6		13.5		12.7	

(1) The enable time is a calculated value, derived using the formula shown in the *Enable Times* section.

7.8 Switching Characteristics (V_{CCA} = 3.3 V ± 0.3 V)

over recommended operating free-air temperature range, V_{CCA} = 3.3 V ± 0.3 V (see Figure 9)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CCB} = 1.8 V ±0.15 V		V_{CCB} = 2.5 V ±0.2 V		V_{CCB} = 3.3 V ±0.3 V		V_{CCB} = 5 V ±0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	A	B	2.1	15.5	1.4	8	0.7	5.8	0.7	4.4	ns
t_{PHL}			2	12.6	1.3	7	0.8	5	0.7	4	
t_{PLH}	B	A	1.7	8.3	1.3	6.4	0.7	5.8	0.6	5.4	ns
t_{PHL}			1.8	7.1	1.3	5.4	0.8	5	0.7	4.5	
t_{PHZ}	DIR	A	2.9	7.3	3	7.3	2.8	7.3	3.4	7.3	ns
t_{PLZ}			1.8	5.6	1.6	5.6	2.2	5.7	2.2	5.7	
t_{PHZ}	DIR	B	5.4	20.5	3.9	10.1	2.9	8.8	2.4	6.8	ns
t_{PLZ}			3.3	14.5	2.9	7.8	2.4	7.1	1.7	4.9	
t_{PZH} (1)	DIR	A		22.8		14.2		12.9		10.3	ns
t_{PZL} (1)				27.6		15.5		13.8		11.3	
t_{PZH} (1)	DIR	B		21.1		13.6		11.5		10.1	ns
t_{PZL} (1)				19.9		14.3		12.3		11.3	

(1) The enable time is a calculated value, derived using the formula shown in the *Enable Times* section.

7.9 Switching Characteristics (V_{CCA} = 5 V ±0.5 V)

over recommended operating free-air temperature range, V_{CCA} = 5 V ±0.5 V (see Figure 9)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CCB} = 1.8 V ±0.15 V		V_{CCB} = 2.5 V ±0.2 V		V_{CCB} = 3.3 V ±0.3 V		V_{CCB} = 5 V ±0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	A	B	1.9	15.1	1	7.5	0.6	5.4	0.5	3.9	ns
t_{PHL}			1.8	12.2	0.9	6.2	0.7	4.5	0.5	3.5	
t_{PLH}	B	A	1.4	7.2	1	5.1	0.7	4.4	0.5	3.9	ns
t_{PHL}			1.7	7	0.9	4.6	0.7	4	0.5	3.5	
t_{PHZ}	DIR	A	2.1	5.4	2.2	5.4	2.2	5.5	2.2	5.4	ns
t_{PLZ}			0.9	3.8	1	3.8	1	3.7	0.9	3.7	
t_{PHZ}	DIR	B	4.8	20.2	2.5	9.8	1	8.5	2.5	6.5	ns
t_{PLZ}			4.2	14.8	2.5	7.4	2.5	7	1.6	4.5	
t_{PZH} (1)	DIR	A		22		12.5		11.4		8.4	ns
t_{PZL} (1)				27.2		14.4		12.5		10	
t_{PZH} (1)	DIR	B		18.9		11.3		9.1		7.6	ns
t_{PZL} (1)				17.6		11.6		10		8.6	

(1) The enable time is a calculated value, derived using the formula shown in the *Enable Times* section.

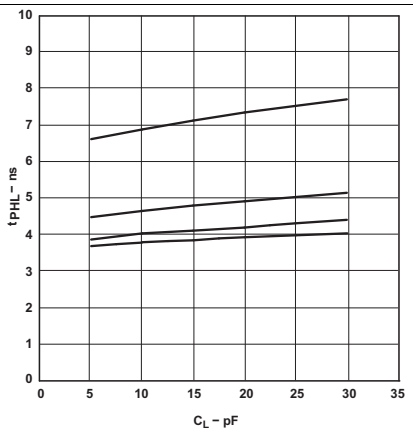
7.10 Operating Characteristics

T_A = 25°C

PARAMETER		TEST CONDITIONS	V_{CCA} = V_{CCB} = 1.8 V	V_{CCA} = V_{CCB} = 2.5 V	V_{CCA} = V_{CCB} = 3.3 V	V_{CCA} = V_{CCB} = 5 V	UNIT
			TYP	TYP	TYP	TYP	
C_{pdA} (1)	A-port input, B-port output	C_L = 0 pF, f = 10 MHz, $t_r = t_f$ = 1 ns	3	4	4	4	pF
	B-port input, A-port output		18	19	20	21	
C_{pdB} (1)	A-port input, B-port output	C_L = 0 pF, f = 10 MHz, $t_r = t_f$ = 1 ns	18	19	20	21	pF
	B-port input, A-port output		3	4	4	4	

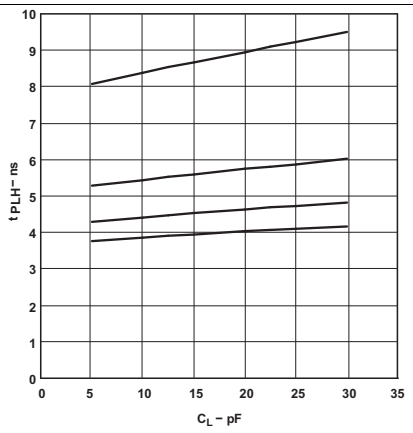
(1) Power dissipation capacitance per transceiver

7.11 Typical Characteristics



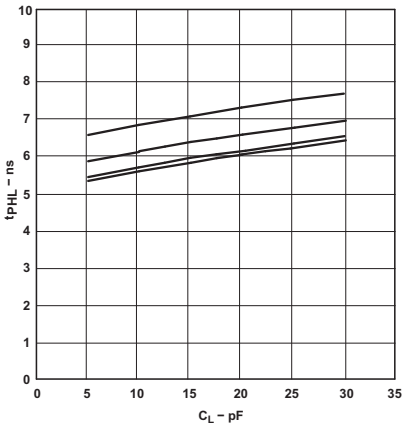
T_A = 25°C, V_{CCA} = 1.8 V

Figure 1. Typical Propagation Delay (A to B) vs Load Capacitance



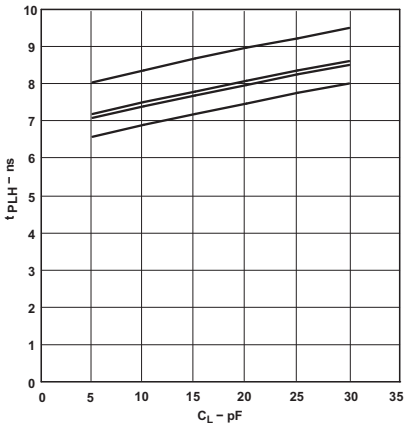
T_A = 25°C, V_{CCA} = 1.8 V

Figure 2. Typical Propagation Delay (B to A) vs Load Capacitance



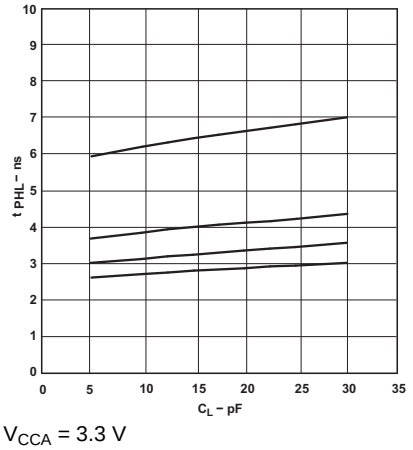
T_A = 25°C, V_{CCA} = 2.5 V

Figure 3. Typical Propagation Delay (A to B) vs Load Capacitance



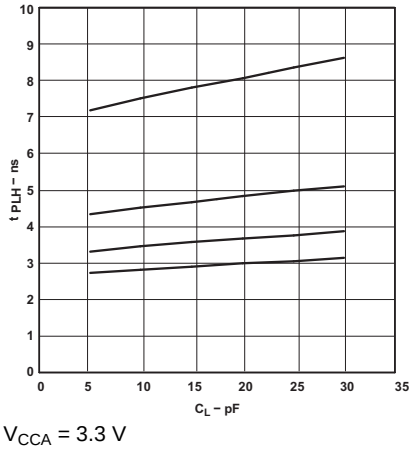
T_A = 25°C, V_{CCA} = 2.5 V

Figure 4. Typical Propagation Delay (B to A) vs Load Capacitance



T_A = 25°C, V_{CCA} = 3.3 V

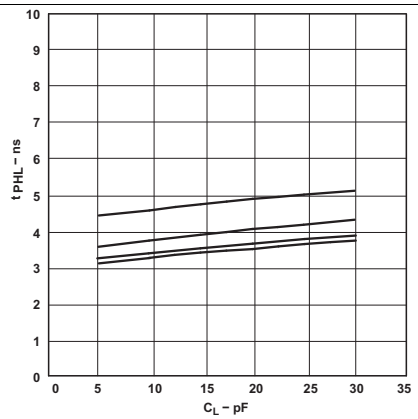
Figure 5. Typical Propagation Delay (A to B) vs Load Capacitance



T_A = 25°C, V_{CCA} = 3.3 V

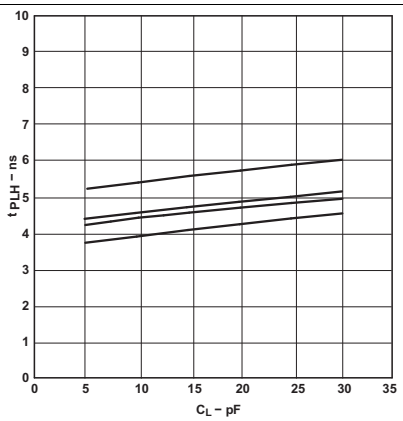
Figure 6. Typical Propagation Delay (B to A) vs Load Capacitance

Typical Characteristics (continued)



T_A = 25°C, V_{CCA} = 5 V

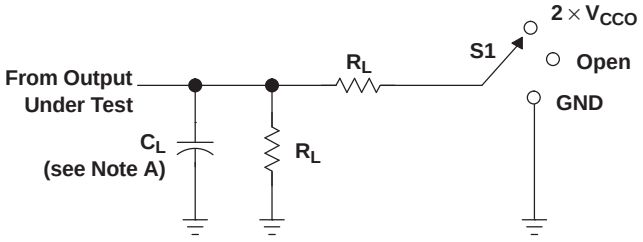
Figure 7. Typical Propagation Delay (A to B) vs Load Capacitance



T_A = 25°C, V_{CCA} = 5 V

Figure 8. Typical Propagation Delay (B to A) vs Load Capacitance

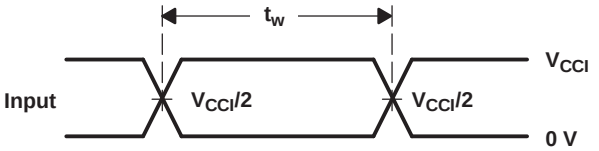
8 Parameter Measurement Information



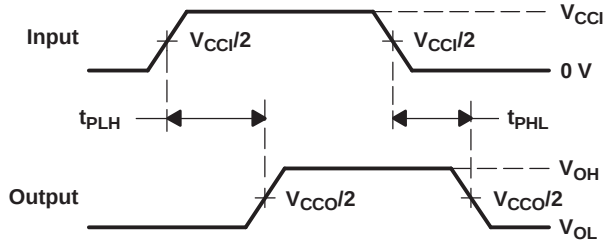
LOAD CIRCUIT

TEST	S1
t_{pd}	Open
t_{PLZ}/t_{PZL}	$2 \times V_{CCO}$
t_{PHZ}/t_{PZH}	GND

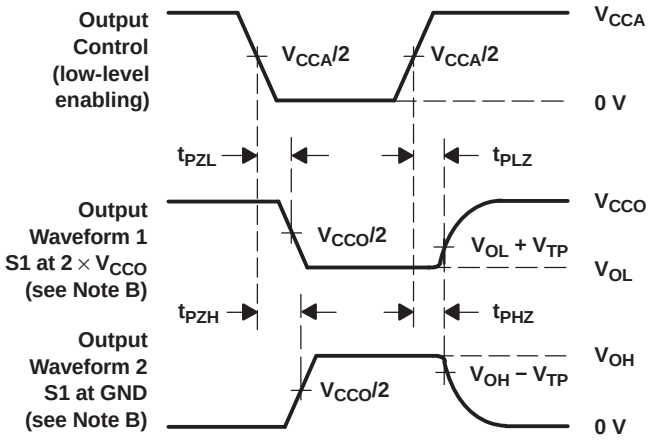
V_{CCO}	C_L	R_L	V_{TP}
1.8 V ± 0.15 V	15 pF	2 kΩ	0.15 V
2.5 V ± 0.2 V	15 pF	2 kΩ	0.15 V
3.3 V ± 0.3 V	15 pF	2 kΩ	0.3 V
5 V ± 0.5 V	15 pF	2 kΩ	0.3 V



VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES

NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, dv/dt ≥ 1 V/ns.
D. The outputs are measured one at a time, with one transition per measurement.
E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
F. t_{PZL} and t_{PZH} are the same as t_{en}.
G. t_{PLH} and t_{PHL} are the same as t_{pd}.
H. V_{CCI} is the V_{CC} associated with the input port.
I. V_{CCO} is the V_{CC} associated with the output port.
J. All parameters and waveforms are not applicable to all devices.

Figure 9. Load Circuit and Voltage Waveforms

9 Detailed Description

9.1 Overview

The SN74LVC1T45 is single-bit, dual-supply, non-inverting voltage level translation. Pin A and that direction control pin (DIR) are supported by V_{CCA} and pin B is supported by V_{CCB}. The A port is able to accept I/O voltages ranging from 1.65 V to 5.5 V, while the B port can accept I/O voltages from 1.65 V to 5.5 V. The high on the DIR allows data transmissions from A to B and a low on the DIR allows data transmissions from B to A.

9.2 Functional Block Diagram

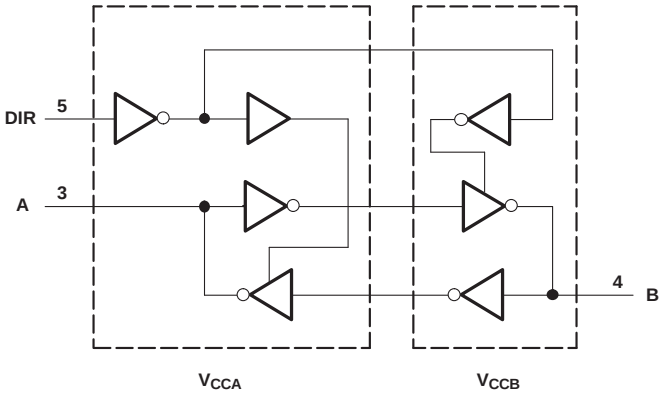


Figure 10. Logic Diagram (Positive Logic)

9.3 Feature Description

9.3.1 Fully Configurable Dual-Rail Design Allows Each Port to Operate Over the Full 1.65-V to 5.5-V Power-Supply Range

Both V_{CCA} and V_{CCB} can be supplied at any voltage between 1.65 V and 5.5 V, making the device suitable for translating between any of the voltage nodes (1.8-V, 2.5-V, 3.3-V and 5-V).

9.3.2 Support High Speed Translation

SN74LVC1T45 can support high data rate applications. The translated signal data rate can be up to 420 Mbps when the signal is translated from 3.3 V to 5 V.

9.3.3 I_{off} Supports Partial Power-Down Mode Operation

I_{off} will prevent backflow current by disabling I/O output circuits when device is in partial-power-down mode.

9.4 Device Functional Modes

Table 1. Function Table(1)

INPUT DIR	OPERATION
L	B data to A bus
H	A data to B bus

(1) Input circuits of the data I/Os always are active.

10 Applications and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

The SN74LVC1T45 device can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another. The max data rate can be up to 420 Mbps when device translates signals from 3.3 V to 5 V.

10.2 Typical Application

10.2.1 Unidirectional Logic Level-Shifting Application

Figure 11 shows an example of the SN74LVC1T45 being used in a unidirectional logic level-shifting application.

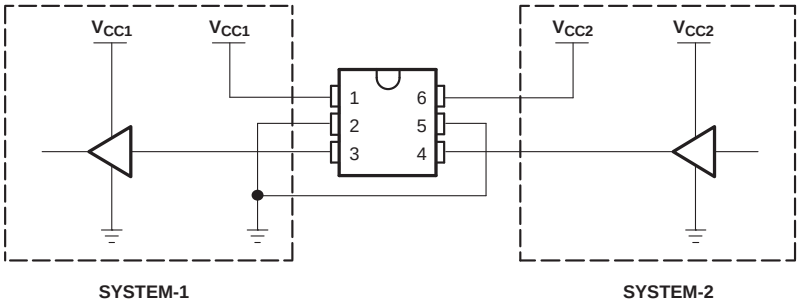


Figure 11. Unidirectional Logic Level-Shifting Application

10.2.1.1 Design Requirements

For this design example, use the parameters listed in Table 2.

Table 2. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	1.65 V to 5.5 V
Output voltage range	1.65 V to 5.5 V

10.2.1.2 Detailed Design Procedure

To begin the design process, determine the following:

- Input voltage range
  - Use the supply voltage of the device that is driving the SN74LVC1T45 device to determine the input voltage range. For a valid logic high the value must exceed the V_{IH} of the input port. For a valid logic low the value must be less than the V_{IL} of the input port.
- Output voltage range
  - Use the supply voltage of the device that the SN74LVC1T45 device is driving to determine the output voltage range.

10.2.1.3 Application Curve

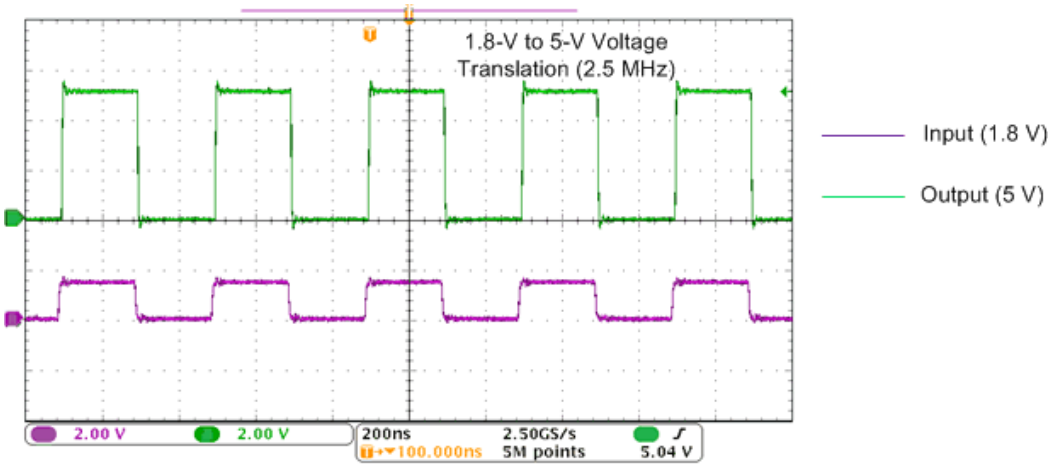


Figure 12. Translation Up (1.8 V to 5 V) at 2.5 MHz

10.2.2 Bidirectional Logic Level-Shifting Application

Figure 13 shows the SN74LVC1T45 being used in a bidirectional logic level-shifting application. Since the SN74LVC1T45 does not have an output-enable ($\overline{OE}$) pin, the system designer should take precautions to avoid bus contention between SYSTEM-1 and SYSTEM-2 when changing directions.

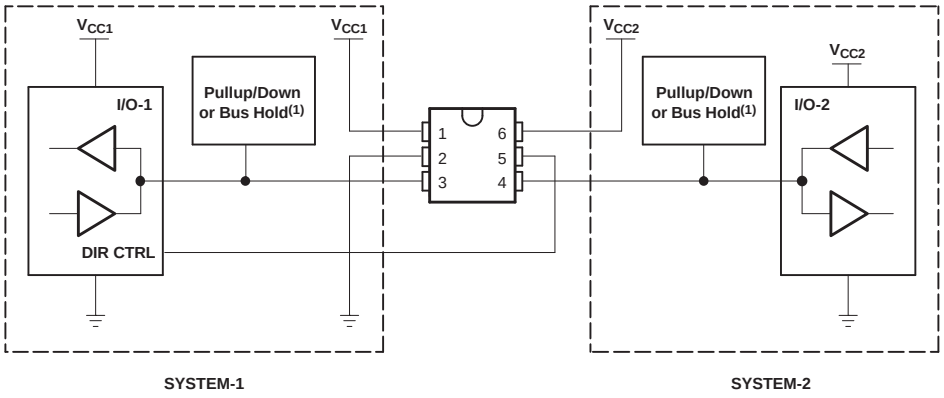


Figure 13. Bidirectional Logic Level-Shifting Application

10.2.2.1 Design Requirements

Please refer to *Design Requirements*.

10.2.2.2 Detailed Design Procedure

Table 3 shows data transmission from SYSTEM-1 to SYSTEM-2 and then from SYSTEM-2 to SYSTEM-1.

Table 3. SYSTEM-1 and SYSTEM-2 Data Transmission

STATE	DIR CTRL	I/O-1	I/O-2	DESCRIPTION
1	H	Out	In	SYSTEM-1 data to SYSTEM-2
2	H	Hi-Z	Hi-Z	SYSTEM-2 is getting ready to send data to SYSTEM-1. I/O-1 and I/O-2 are disabled. The bus-line state depends on pullup or pulldown.(1)
3	L	Hi-Z	Hi-Z	DIR bit is flipped. I/O-1 and I/O-2 still are disabled. The bus-line state depends on pullup or pulldown.(1)
4	L	Out	In	SYSTEM-2 data to SYSTEM-1

(1) SYSTEM-1 and SYSTEM-2 must use the same conditions, i.e., both pullup or both pulldown.

10.2.2.2.1 Enable Times

Calculate the enable times for the SN74LVC1T45 using the following formulas:

- t_{PZH} (DIR to A) = t_{PLZ} (DIR to B) + t_{PLH} (B to A)
- t_{PZL} (DIR to A) = t_{PHZ} (DIR to B) + t_{PHL} (B to A)
- t_{PZH} (DIR to B) = t_{PLZ} (DIR to A) + t_{PLH} (A to B)
- t_{PZL} (DIR to B) = t_{PHZ} (DIR to A) + t_{PHL} (A to B)

In a bidirectional application, these enable times provide the maximum delay from the time the DIR bit is switched until an output is expected. For example, if the SN74LVC1T45 initially is transmitting from A to B, then the DIR bit is switched; the B port of the device must be disabled before presenting it with an input. After the B port has been disabled, an input signal applied to it appears on the corresponding A port after the specified propagation delay.

10.2.2.3 Application Curve

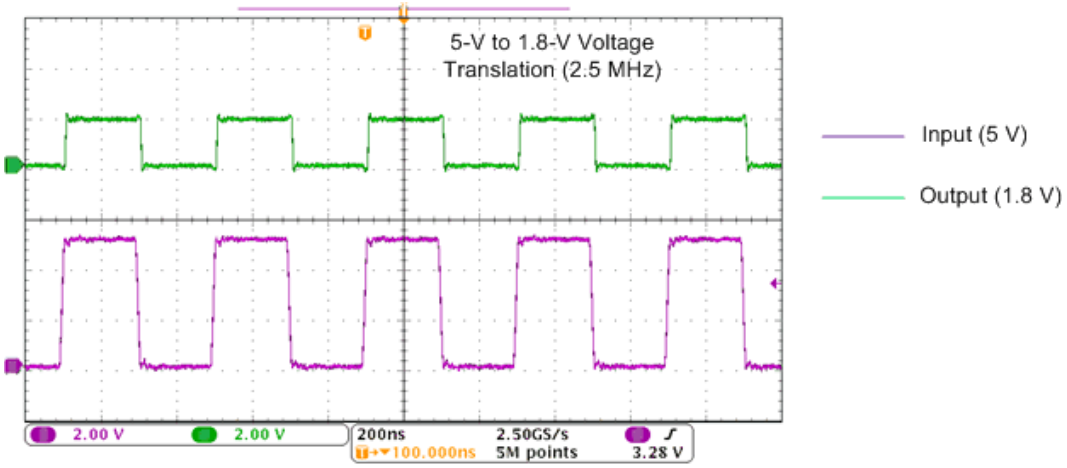


Figure 14. Translation Down (5V to 1.8 V) at 2.5 MHz

11 Power Supply Recommendations

The SN74LVC1T45 device uses two separate configurable power-supply rails, V_{CCA} and V_{CCB}. V_{CCA} accepts any supply voltage from 1.65 V to 5.5 V and V_{CCB} accepts any supply voltage from 1.65 V to 5.5 V. The A port and B port are designed to track V_{CCA} and V_{CCB}, respectively allowing for low-voltage bidirectional translation between any of the 1.8-V, 2.5-V, 3.3-V and 5-V voltage nodes.

12 Layout

12.1 Layout Guidelines

To ensure reliability of the device, the following common printed-circuit board layout guidelines are recommended:

- Bypass capacitors should be used on power supplies.
- Short trace lengths should be used to avoid excessive loading.
- Placing pads on the signal paths for loading capacitors or pullup resistors to help adjust rise and fall times of signals depends on the system requirements

12.2 Layout Example

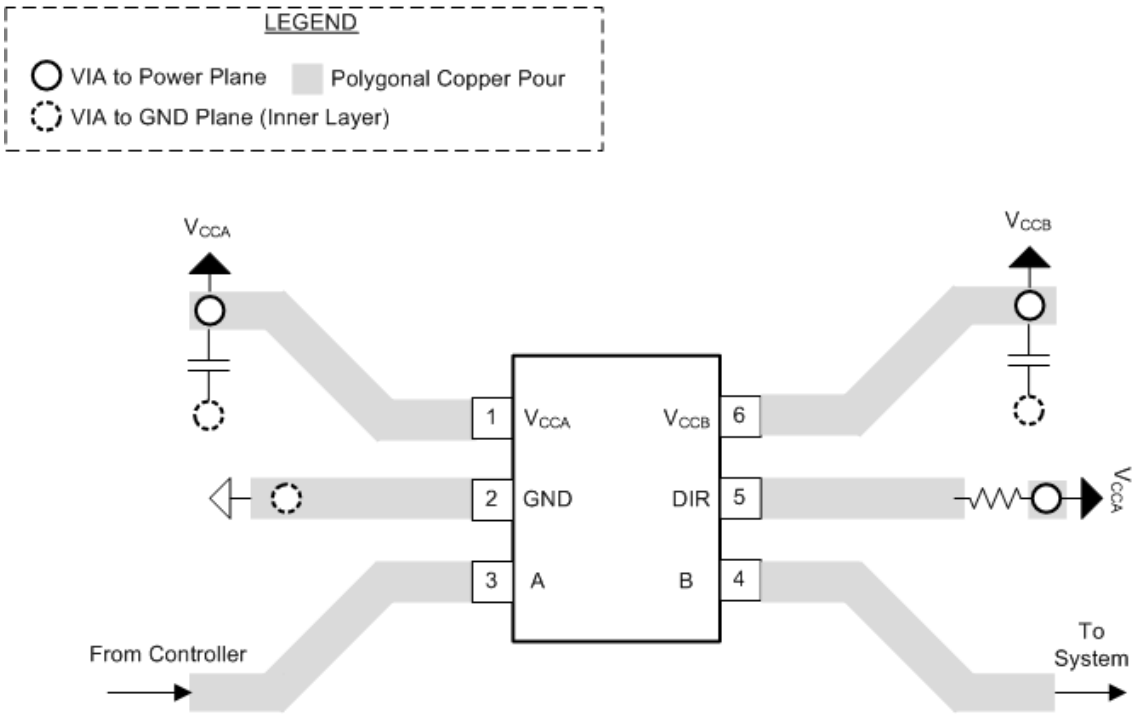


Figure 15. Layout Example

13 Device and Documentation Support

13.1 Trademarks

NanoFree is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

13.2 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.3 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVC1T45DBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(CT15 ~ CT1F ~ CT1R)	Samples
SN74LVC1T45DBVRE4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(CT15 ~ CT1F ~ CT1R)	Samples
SN74LVC1T45DBVRG4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(CT15 ~ CT1F ~ CT1R)	Samples
SN74LVC1T45DBVT	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(CT15 ~ CT1F ~ CT1R)	Samples
SN74LVC1T45DBVTG4	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(CT15 ~ CT1F ~ CT1R)	Samples
SN74LVC1T45DCKR	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(TA5 ~ TAF ~ TAR)	Samples
SN74LVC1T45DCKRE4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(TA5 ~ TAF ~ TAR)	Samples
SN74LVC1T45DCKRG4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(TA5 ~ TAF ~ TAR)	Samples
SN74LVC1T45DCKT	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(TA5 ~ TAF ~ TAR)	Samples
SN74LVC1T45DCKTE4	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(TA5 ~ TAF ~ TAR)	Samples
SN74LVC1T45DCKTG4	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(TA5 ~ TAF ~ TAR)	Samples
SN74LVC1T45DPKR	ACTIVE	USON	DPK	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TA7	Samples
SN74LVC1T45DRLR	ACTIVE	SOT	DRL	6	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(TA7 ~ TAR)	Samples
SN74LVC1T45DRLRG4	ACTIVE	SOT	DRL	6	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(TA7 ~ TAR)	Samples
SN74LVC1T45YZPR	ACTIVE	DSBGA	YZP	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(TA2 ~ TA7 ~ TAN)	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

OTHER QUALIFIED VERSIONS OF SN74LVC1T45 :

- Automotive: SN74LVC1T45-Q1
- Enhanced Product: SN74LVC1T45-EP

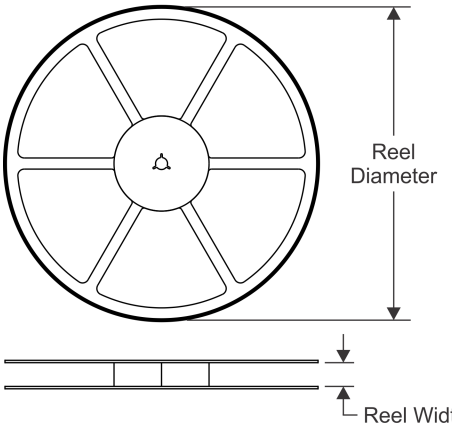
NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

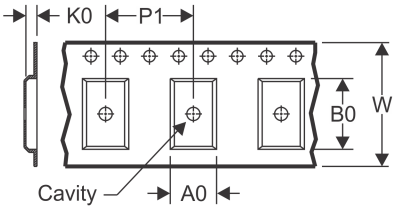
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

TAPE AND REEL INFORMATION

REEL DIMENSIONS

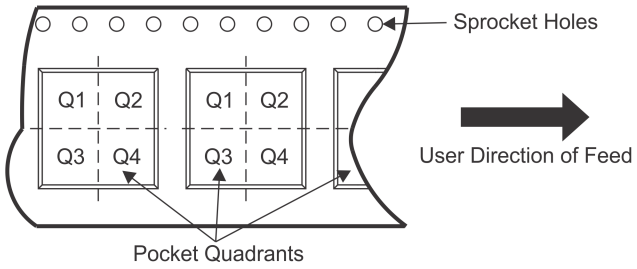


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

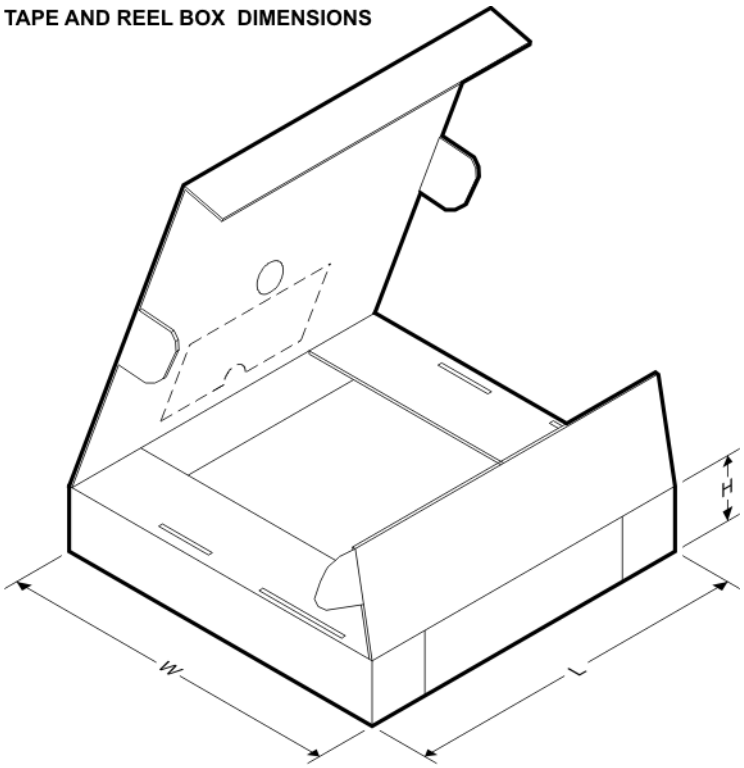
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1T45DBVR	SOT-23	DBV	6	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1T45DBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1T45DBVT	SOT-23	DBV	6	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1T45DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74LVC1T45DCKR	SC70	DCK	6	3000	180.0	8.4	2.41	2.41	1.2	4.0	8.0	Q3
SN74LVC1T45DCKT	SC70	DCK	6	250	180.0	8.4	2.41	2.41	1.2	4.0	8.0	Q3
SN74LVC1T45DCKT	SC70	DCK	6	250	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74LVC1T45DCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74LVC1T45DPKR	USON	DPK	6	5000	180.0	9.5	1.75	1.75	0.7	4.0	8.0	Q2
SN74LVC1T45DRLR	SOT	DRL	6	4000	180.0	9.5	1.78	1.78	0.69	4.0	8.0	Q3
SN74LVC1T45DRLR	SOT	DRL	6	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
SN74LVC1T45YZPR	DSBGA	YZP	6	3000	178.0	9.2	1.02	1.52	0.63	4.0	8.0	Q1

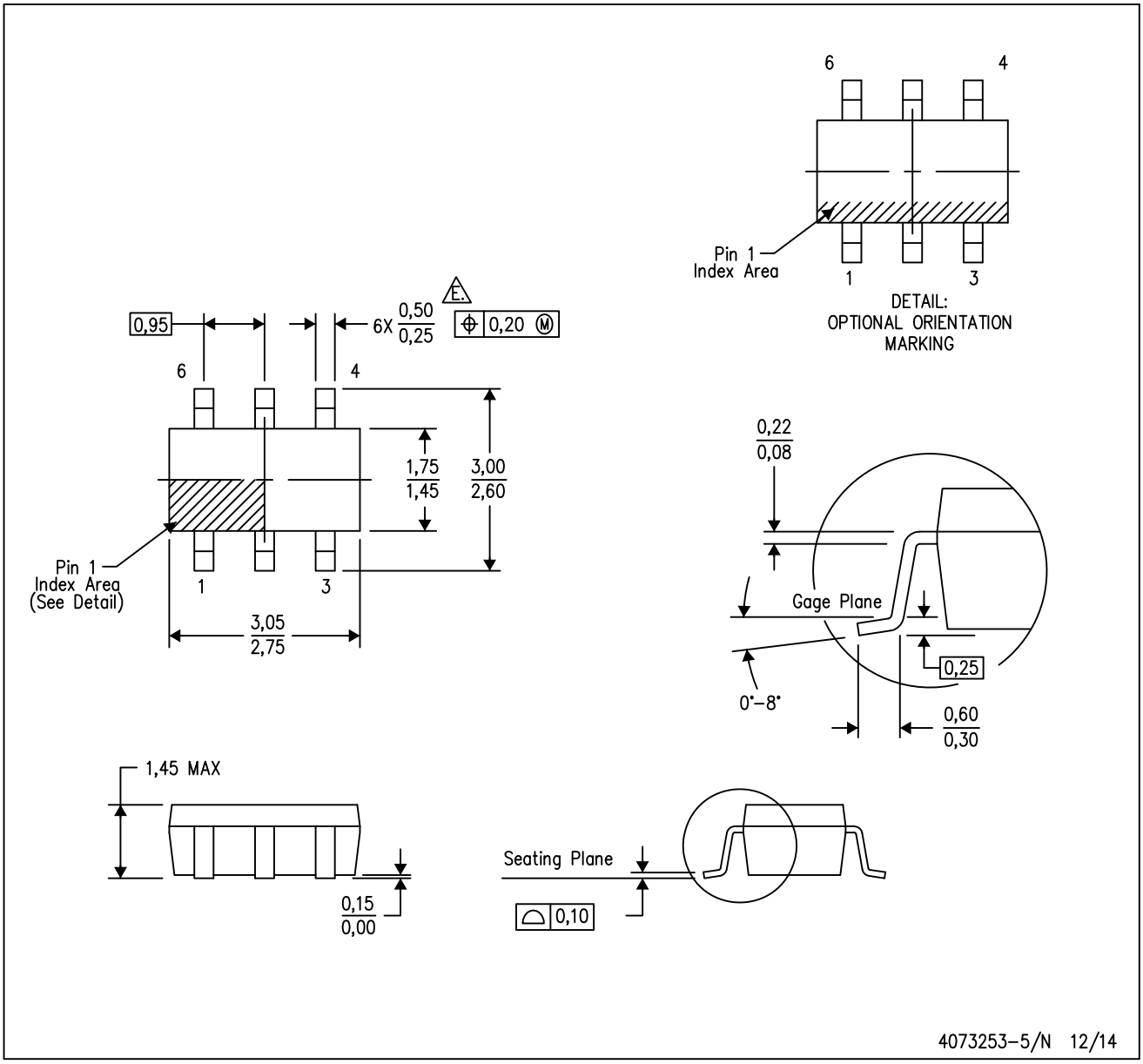
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

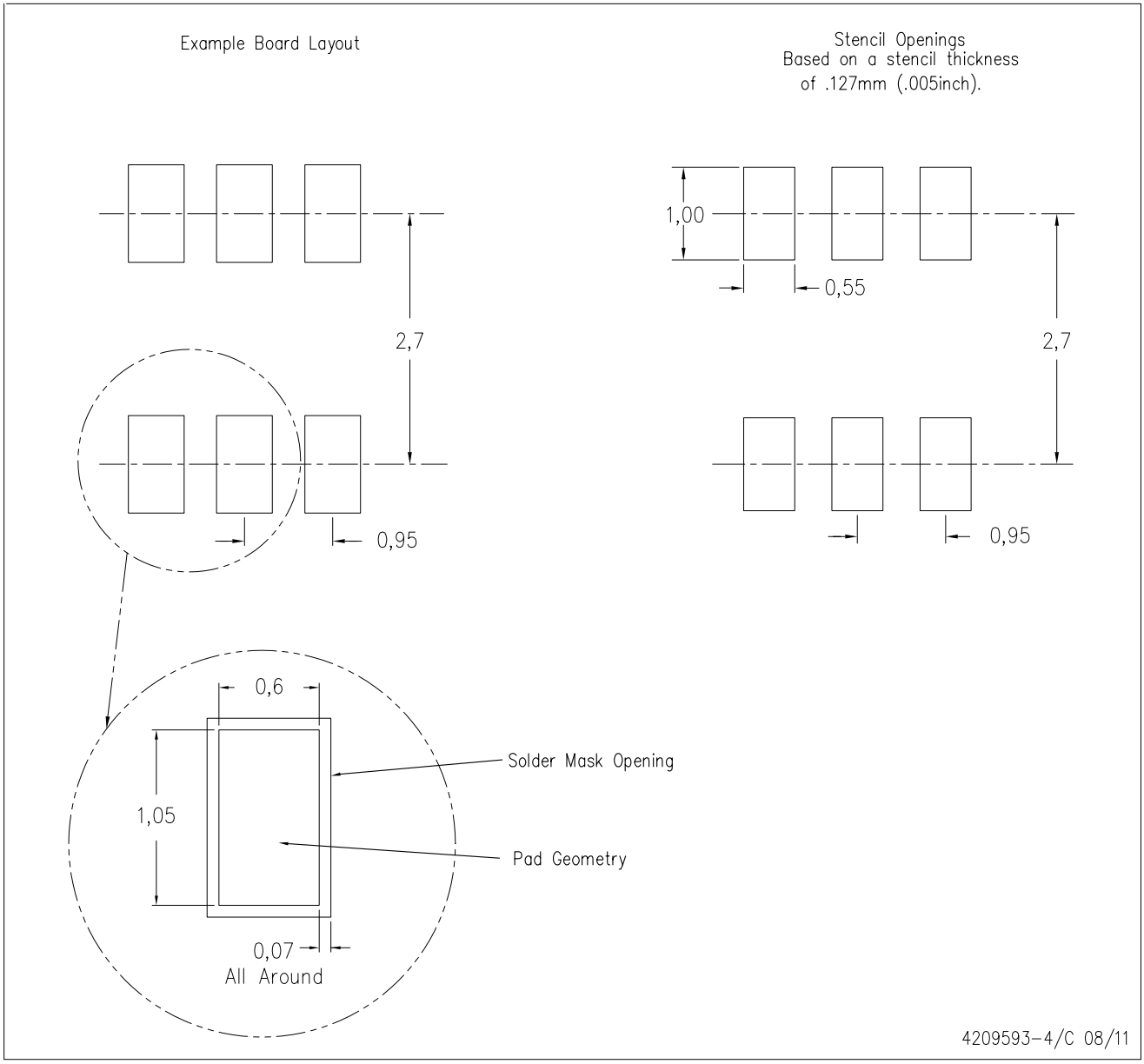
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC1T45DBVR	SOT-23	DBV	6	3000	202.0	201.0	28.0
SN74LVC1T45DBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0
SN74LVC1T45DBVT	SOT-23	DBV	6	250	202.0	201.0	28.0
SN74LVC1T45DCKR	SC70	DCK	6	3000	180.0	180.0	18.0
SN74LVC1T45DCKR	SC70	DCK	6	3000	202.0	201.0	28.0
SN74LVC1T45DCKT	SC70	DCK	6	250	202.0	201.0	28.0
SN74LVC1T45DCKT	SC70	DCK	6	250	180.0	180.0	18.0
SN74LVC1T45DCKT	SC70	DCK	6	250	180.0	180.0	18.0
SN74LVC1T45DPKR	USON	DPK	6	5000	184.0	184.0	19.0
SN74LVC1T45DRLR	SOT	DRL	6	4000	184.0	184.0	19.0
SN74LVC1T45DRLR	SOT	DRL	6	4000	202.0	201.0	28.0
SN74LVC1T45YZPR	DSBGA	YZP	6	3000	220.0	220.0	35.0

DBV (R–PDSO–G6) PLASTIC SMALL–OUTLINE PACKAGE



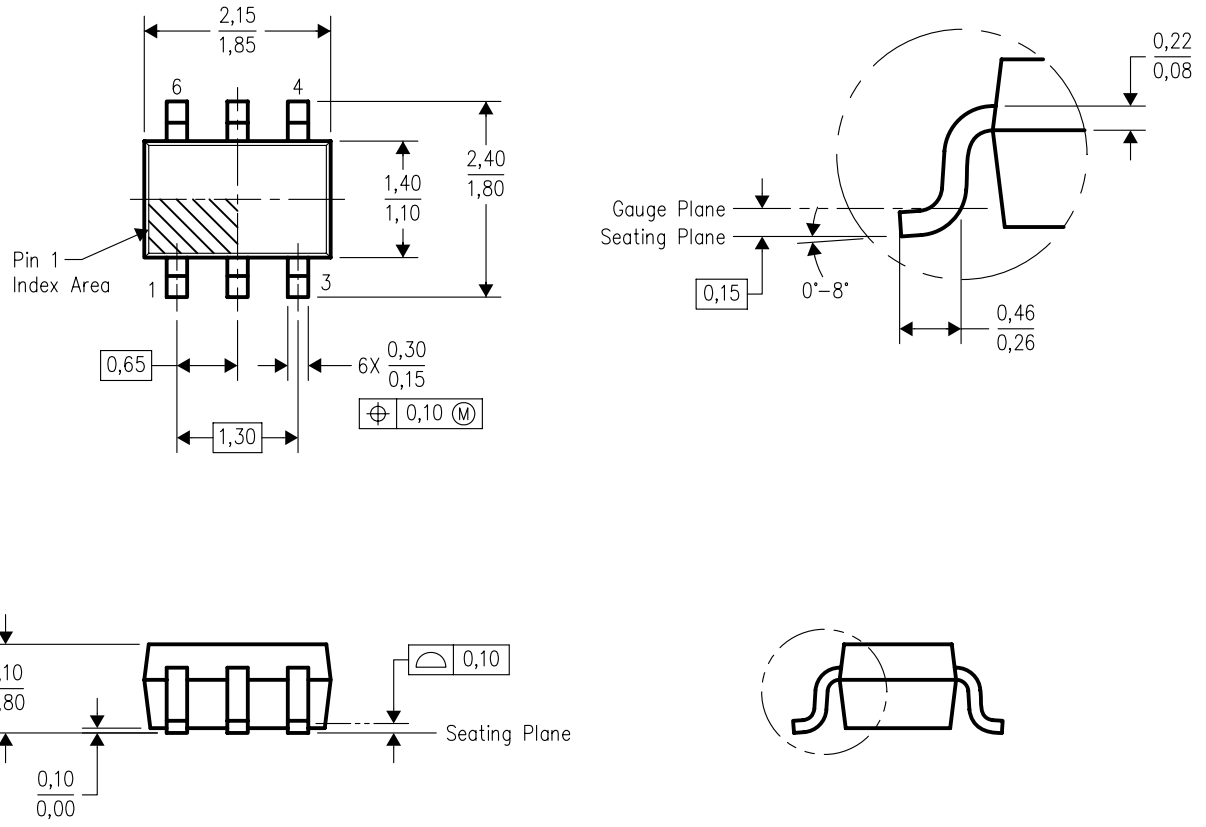
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
E. Falls within JEDEC MO–178 Variation AB, except minimum lead width.

DBV (R–PDSO–G6) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
D. Publication IPC–7351 is recommended for alternate designs.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC–7525 for other stencil recommendations.

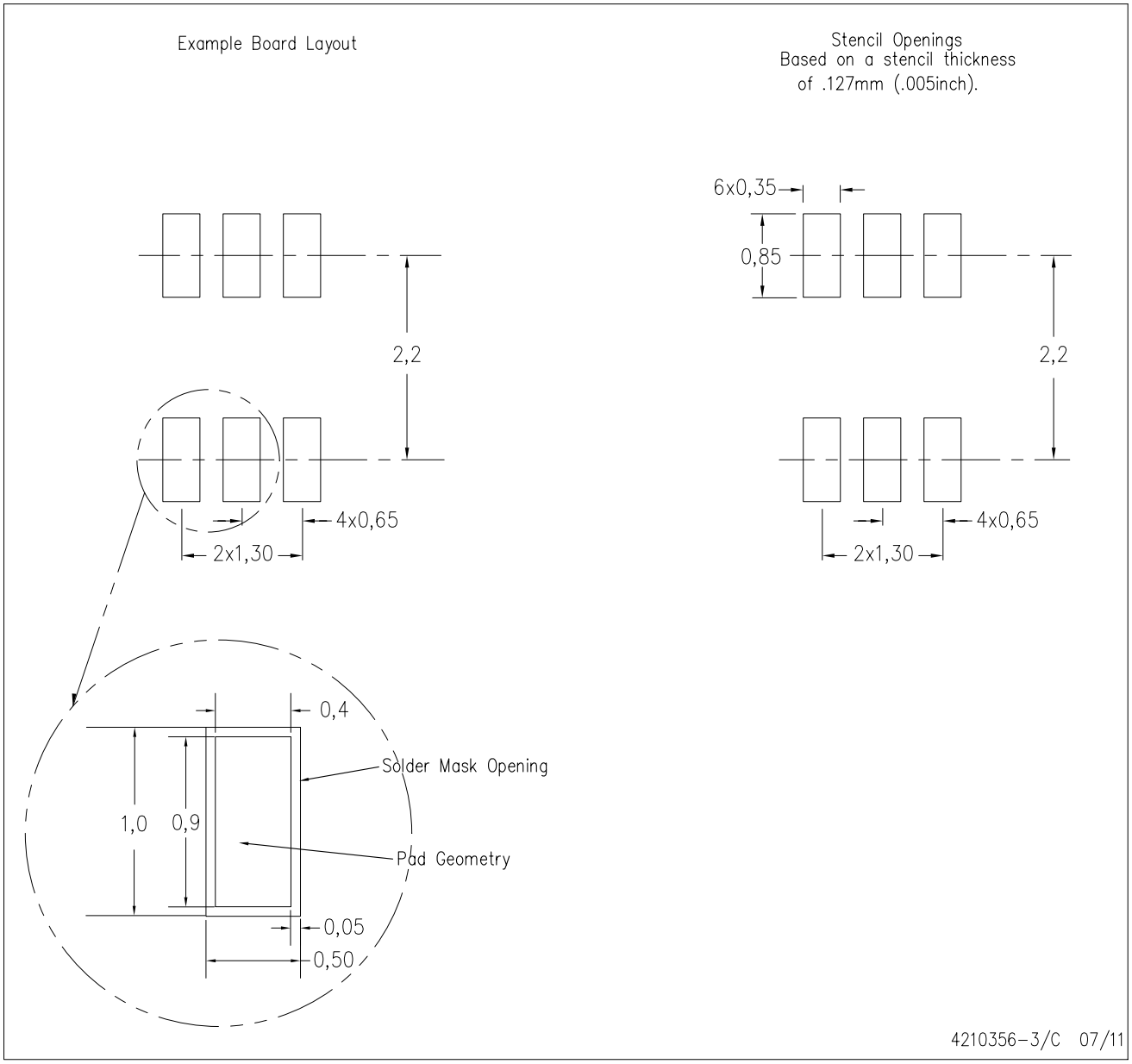
DCK (R–PDSO–G6) PLASTIC SMALL–OUTLINE PACKAGE



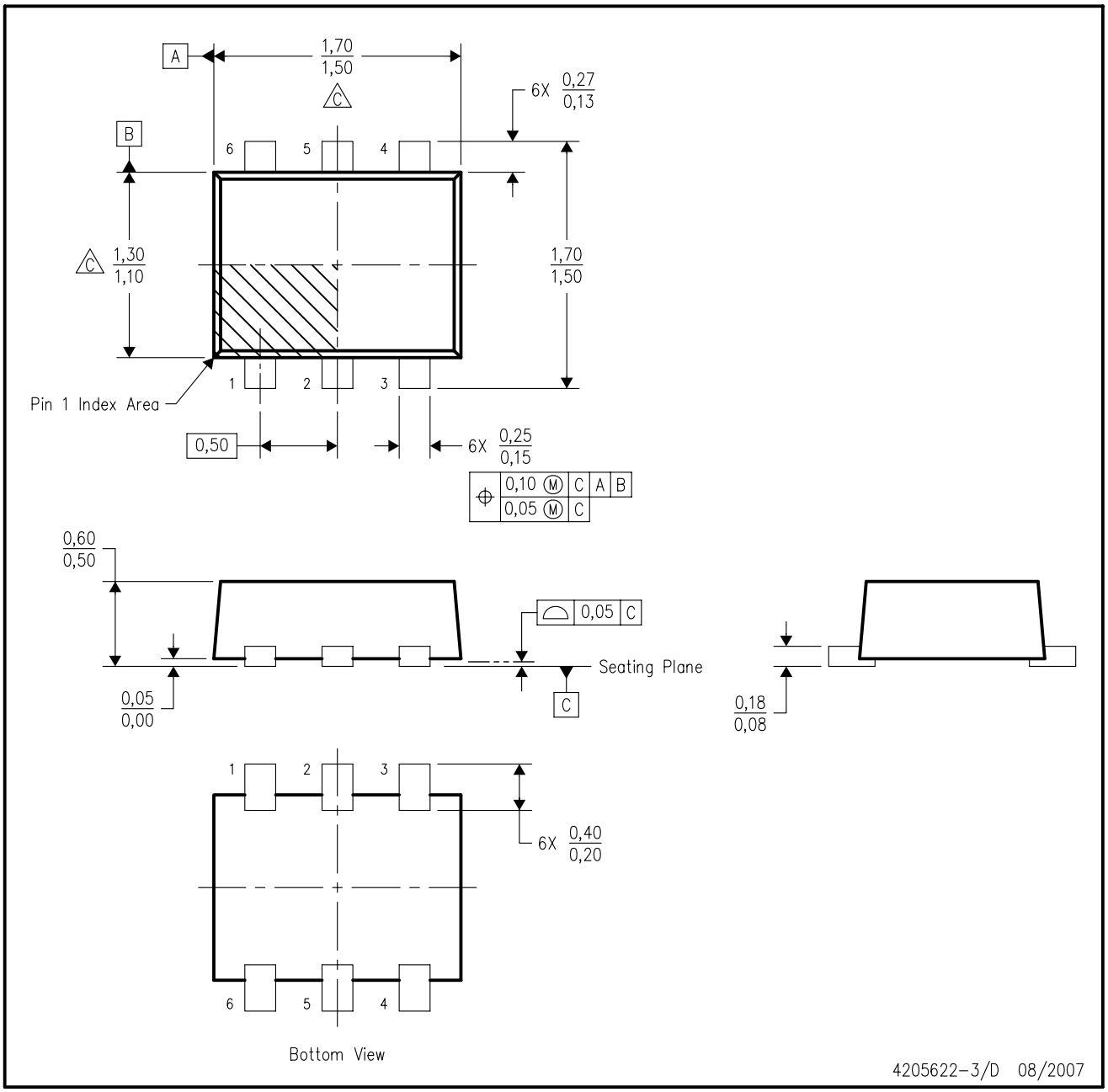
4093553–4/G 01/2007

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
D. Falls within JEDEC MO–203 variation AB.

DCK (R–PDSO–G6) PLASTIC SMALL OUTLINE

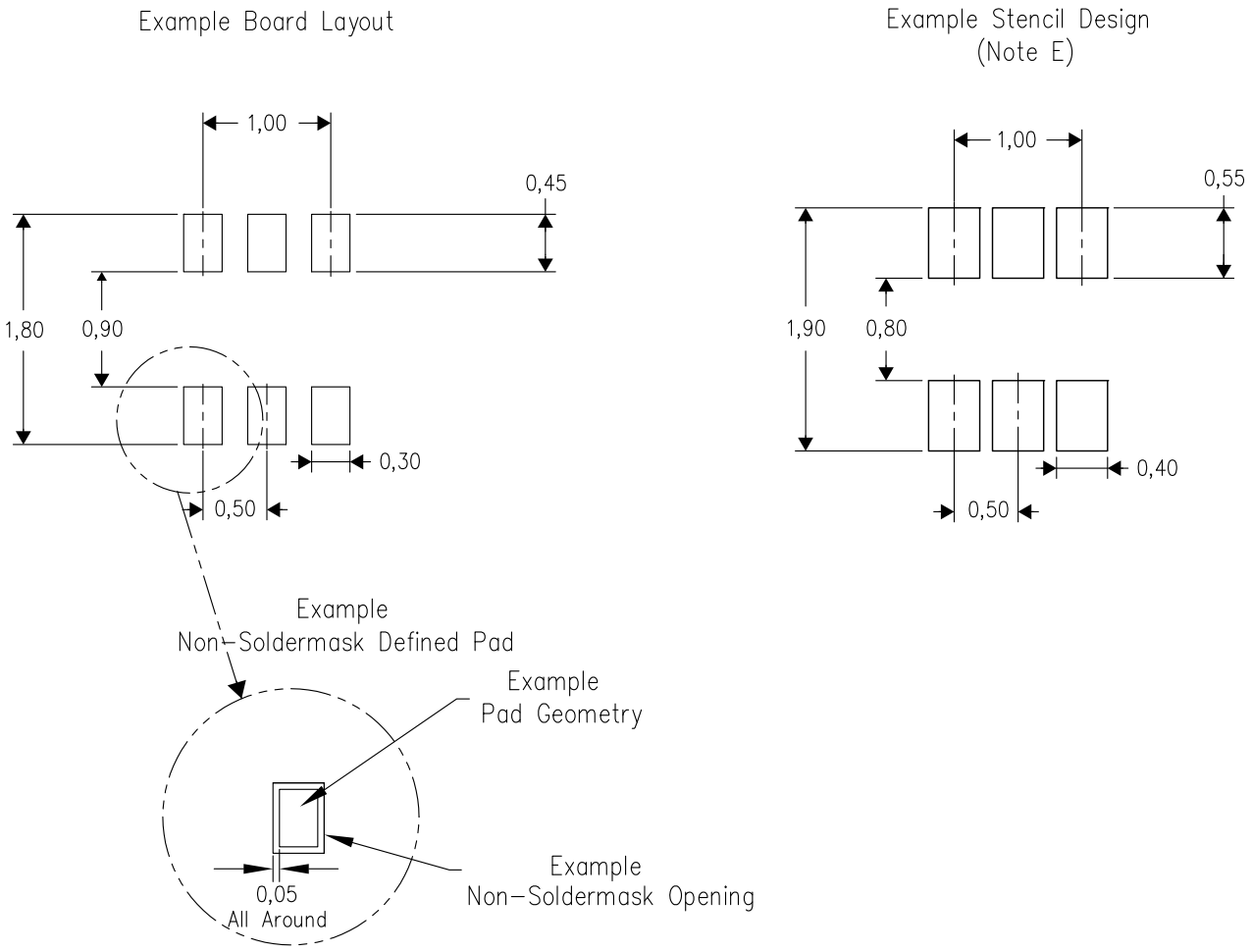


NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
D. Publication IPC–7351 is recommended for alternate designs.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC–7525 for other stencil recommendations.



NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash, interlead flash, protrusions, or gate burrs. Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0,15 per end or side.
D. JEDEC package registration is pending.

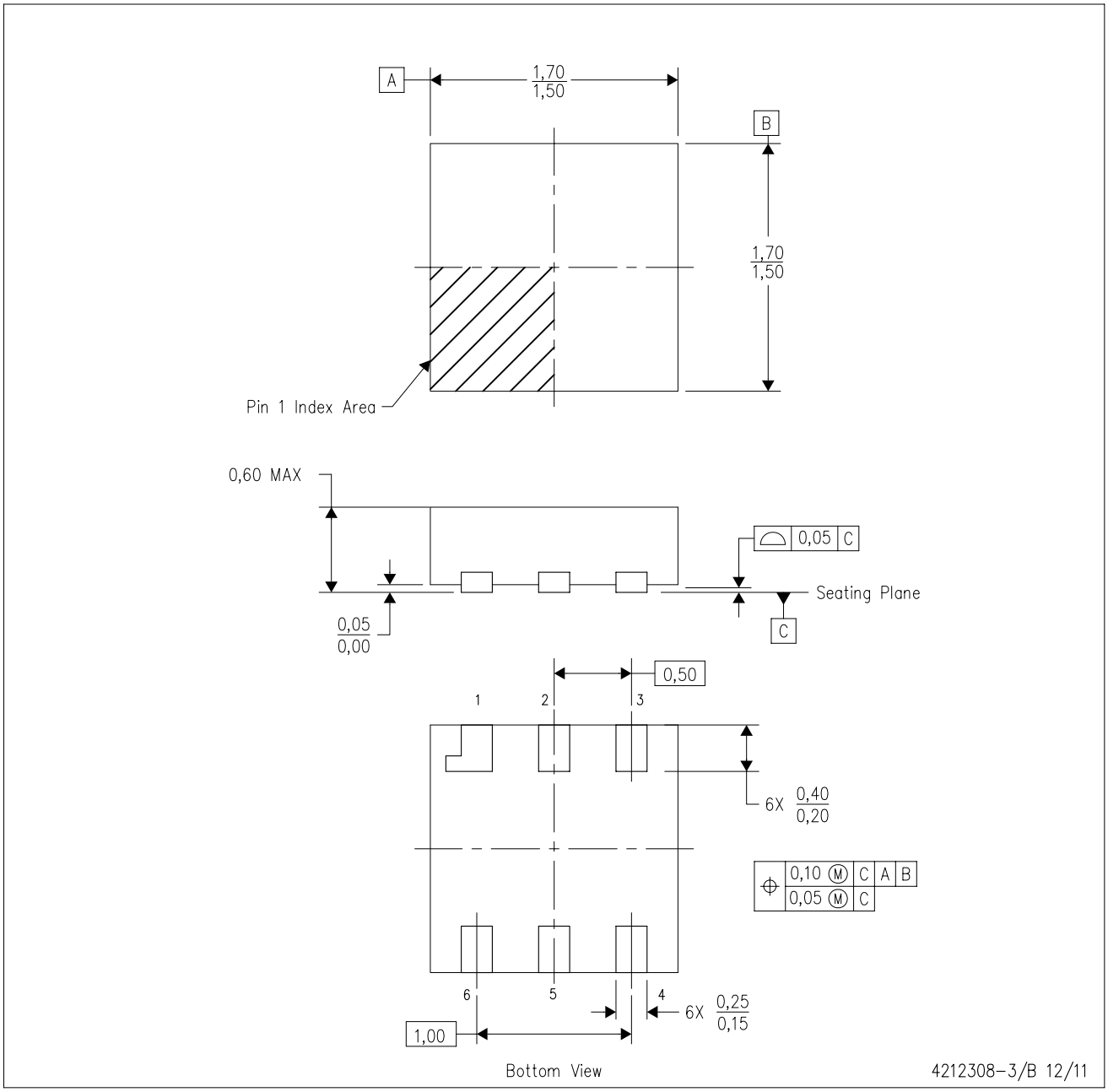
DRL (R–PDSO–N6) PLASTIC SMALL OUTLINE



4208207–3/E 06/12

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
G. Side aperture dimensions over–print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.

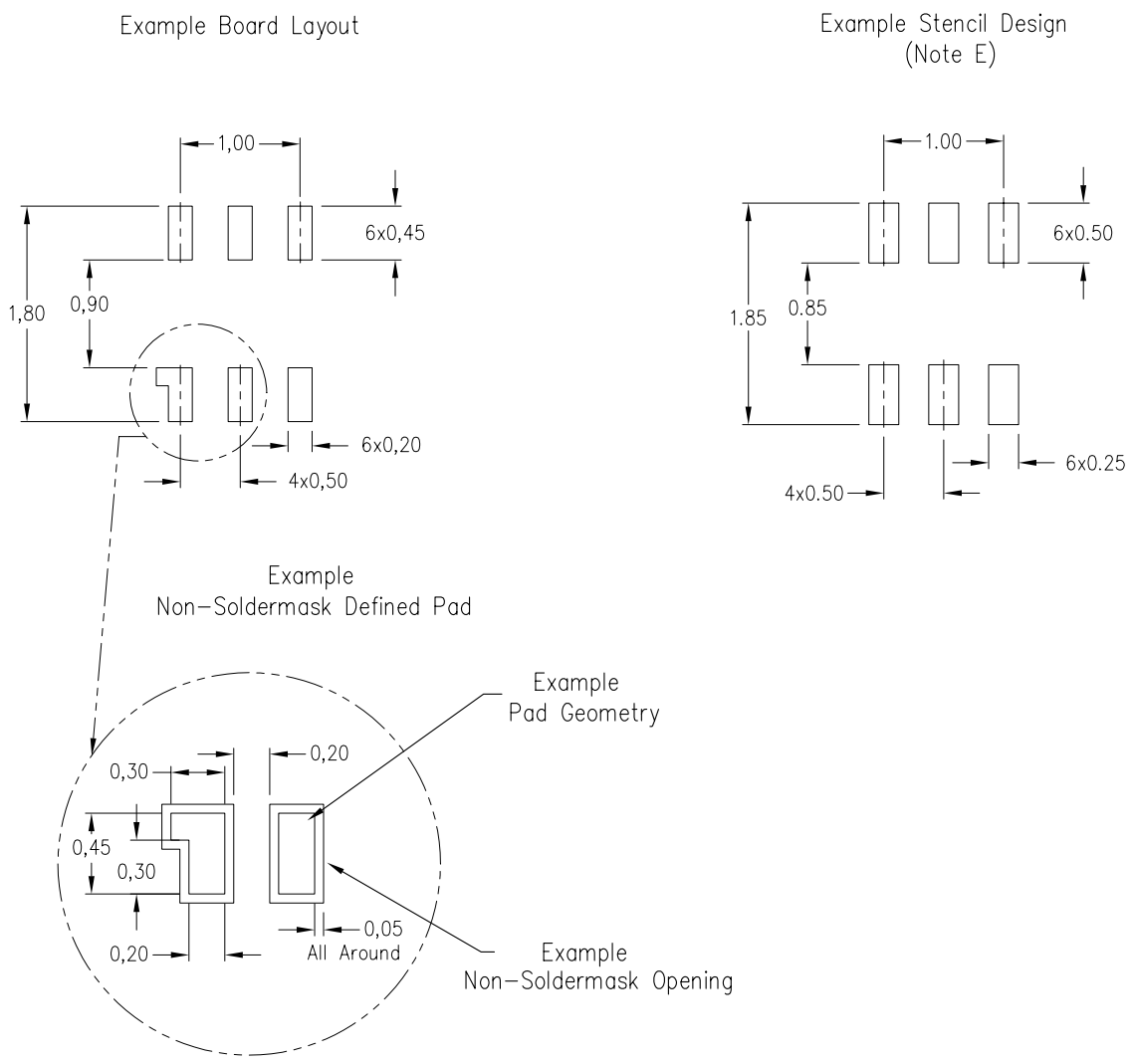
DPK (S–PUSON–N6) PLASTIC SMALL OUTLINE NO–LEAD



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.

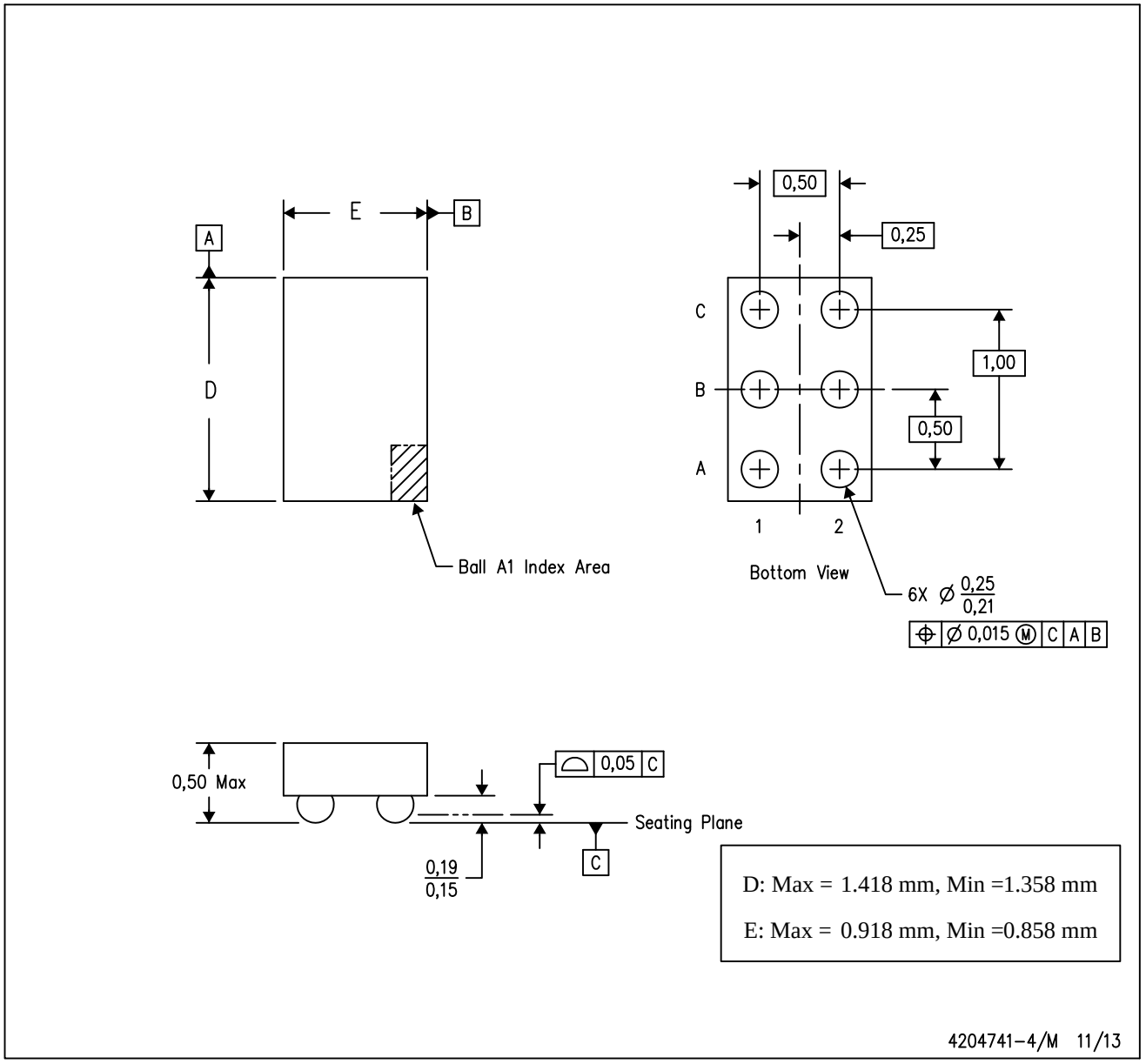
DPK (S–PUSON–N6)

PLASTIC SMALL OUTLINE NO–LEAD



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
G. Side aperture dimensions over–print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.

YZP (R–XBGA–N6) DIE–SIZE BALL GRID ARRAY



NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. NanoFree™ package configuration.

NanoFree is a trademark of Texas Instruments.

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